

Green Products

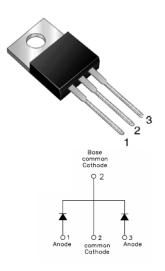
MBR1640CT SCHOTTKY RECTIFIER

Applications:

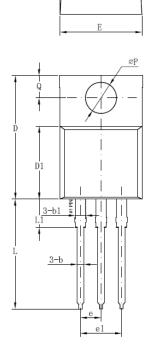
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

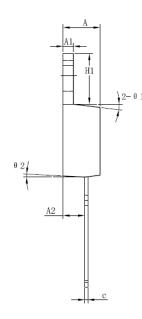
Features:

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions (In mm):





| Symbol | Dimensions in millimeters | | | |
|------------|---------------------------|---------|-------|--|
| - , | Min | Typical | Max | |
| Α | 4.42 | 4.57 | 4.72 | |
| A1 | 1.17 | 1.27 | 1.37 | |
| A2 | 2.59 | 2.69 | 2.89 | |
| b | 0.71 | 0.81 | 0.96 | |
| b1 | | 1.27 | | |
| С | 0.36 | 0.38 | 0.61 | |
| D | 14.94 | 15.24 | 15.54 | |
| D1 | 8.85 | 9.00 | 9.15 | |
| E | 10.01 | 10.16 | 10.31 | |
| е | | 2.54 | | |
| e1 | | 5.06 | | |
| H1 | 6.04 | 6.24 | 6.44 | |
| L | 12.7 | 13.56 | 13.78 | |
| L1 | | 3.5 | | |
| ФР | 3.74 | 3.84 | 4.04 | |
| Q | 2.54 | 2.74 | 2.94 | |
| Θ1 | | 7° | | |
| Θ2 | | 3° | | |
| Θ3 | | 4° | | |

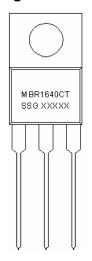
TO-220AB

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •



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Marking Diagram:



Where XXXXX is YYWWL

MBR = Device Type

16 = Forward Current (16A) 40 = Reverse Voltage (40V)

CT = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

| Device | Package | Shipping |
|-----------|-----------|---------------|
| MDD4640CT | TO-220AB | FOr an / tube |
| MBR1640CT | (Pb-Free) | 50pcs / tube |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--------------------------------------------------------------|--------------------|--------------------------------------------------------------|------|-------|
| Peak Inverse Voltage | V_{RWM} | - | 40 | V |
| Average Forward Current (per device) | I _{F(AV)} | 50% duty cycle @T _C =105°C, rectangular wave form | 16 | Α |
| Peak One Cycle Non- Repetitive Surge Current (per leg) | I _{FSM} | 8.3 ms, half Sine pulse | 180 | А |

[•] http://www.smc-diodes.com - sales@ smc-diodes.com •



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Electrical Characteristics:

| Characteristics | Symbol | Condition | Max. | Units |
|----------------------------|-----------------|----------------------------------------------|------|-------|
| Forward Voltage Drop | V _{F1} | @ 16A, Pulse, T _J = 25 °C | 0.85 | V |
| (per leg)* | V_{F2} | @ 16A, Pulse, T _J = 125 °C | 0.75 | V |
| Reverse Current (per leg)* | I _{R1} | @V _R = rated V _R | 1.0 | mA |
| | | T _J = 25 °C | | |
| | I _{R2} | @V _R = rated V _R | 15 | mA |
| | | T _J = 125 °C | | |
| Junction Capacitance | Ст | @V _R = 5V, T _C = 25 °C | 400 | pF |
| (per leg) | | f _{SIG} = 1MHz | | |

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|-----------------------------|------------------|--------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +150 | °C |
| Storage Temperature | T _{stg} | - | -55 to +150 | °C |
| Maximum Thermal | $R_{\theta JC}$ | DC operation | 3 | °C/W |
| Resistance Junction to Case | | | | |
| Approximate Weight | wt | - | 2 | g |
| Case Style | | TO-220AB | | |





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